



# NX1029X

60 / 50 V, 330 / 170 mA N/P-channel Trench MOSFET

28 December 2022

Product data sheet

## 1. General description

Complementary N/P-channel enhancement mode Field-Effect Transistor (FET) in an ultra small and flat lead SOT666 Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

## 2. Features and benefits

- Logic-level compatible
- Very fast switching
- Trench MOSFET technology
- ESD protection up to 2 kV (N-channel) and 1 kV (P-channel)

## 3. Applications

- Level shifter
- Power supply converter
- Loadswitch
- Switching circuits

## 4. Quick reference data

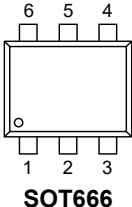
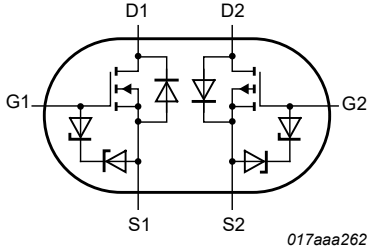
Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>TR1 (N-channel)</b>						
$V_{DS}$	drain-source voltage	$T_j = 25\text{ }^{\circ}\text{C}$	-	-	60	V
$V_{GS}$	gate-source voltage		-20	-	20	V
$I_D$	drain current	$V_{GS} = 10\text{ V}; T_{amb} = 25\text{ }^{\circ}\text{C}$	[1]	-	330	mA
<b>TR1 (N-channel), Static characteristics</b>						
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = 10\text{ V}; I_D = 500\text{ mA}; \text{pulsed}; t_p \leq 300\text{ }\mu\text{s}; \delta \leq 0.01; T_j = 25\text{ }^{\circ}\text{C}$	-	1	1.6	$\Omega$
<b>TR2 (P-channel)</b>						
$V_{DS}$	drain-source voltage	$T_j = 25\text{ }^{\circ}\text{C}$	-	-	-50	V
$V_{GS}$	gate-source voltage		-20	-	20	V
$I_D$	drain current	$V_{GS} = -10\text{ V}; T_{amb} = 25\text{ }^{\circ}\text{C}$	[1]	-	-170	mA
<b>TR2 (P-channel), Static characteristics</b>						
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = -10\text{ V}; I_D = -100\text{ mA}; T_j = 25\text{ }^{\circ}\text{C}$	-	4.5	7.5	$\Omega$

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 1 cm<sup>2</sup>.

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S1	source TR1	 SOT666	 017aaa262
2	G1	gate TR1		
3	D2	drain TR2		
4	S2	source TR2		
5	G2	gate TR2		
6	D1	drain TR1		

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
NX1029X	SOT666	plastic, surface-mounted package; 6 leads; 0.5 mm pitch; 1.6 mm x 1.2 mm x 0.55 mm body	SOT666

7. Marking

Table 4. Marking codes

Type number	Marking code
NX1029X	AD

## 8. Limiting values

**Table 5. Limiting values**

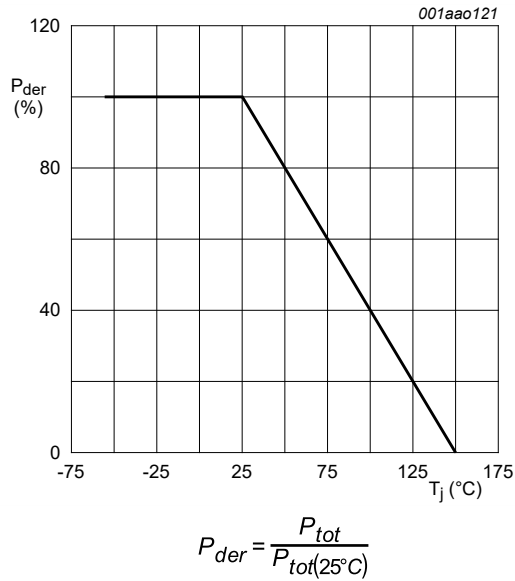
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
TR1 (N-channel)						
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	60	V
V <sub>GS</sub>	gate-source voltage			-20	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 25 °C	[1]	-	330	mA
		V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 100 °C	[1]	-	210	mA
I <sub>DM</sub>	peak drain current	T <sub>amb</sub> = 25 °C; single pulse; t <sub>p</sub> ≤ 10 μs		-	1.2	A
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[2]	-	330	mW
			[1]	-	390	mW
		T <sub>sp</sub> = 25 °C		-	1090	mW
TR2 (P-channel)						
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-50	V
V <sub>GS</sub>	gate-source voltage			-20	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = -10 V; T <sub>amb</sub> = 25 °C	[1]	-	-170	mA
		V <sub>GS</sub> = -10 V; T <sub>amb</sub> = 100 °C	[1]	-	-110	mA
I <sub>DM</sub>	peak drain current	T <sub>amb</sub> = 25 °C; single pulse; t <sub>p</sub> ≤ 10 μs		-	-0.7	A
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[2]	-	330	mW
			[1]	-	390	mW
		T <sub>sp</sub> = 25 °C		-	1090	mW
Per device						
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[2]	-	500	mW
T <sub>j</sub>	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
TR1 (N-channel), Source-drain diode						
I <sub>S</sub>	source current	T <sub>amb</sub> = 25 °C	[2] [1]	-	330	mA
TR2 (P-channel), Source-drain diode						
I <sub>S</sub>	source current	T <sub>amb</sub> = 25 °C	[1]	-	-170	mA
TR1 N-channel), ESD maximum rating						
V <sub>ESD</sub>	electrostatic discharge voltage	HBM	[3]	-	2000	V
TR2 (P-channel), ESD maximum rating						
V <sub>ESD</sub>	electrostatic discharge voltage	HBM	[3]	-	1000	V

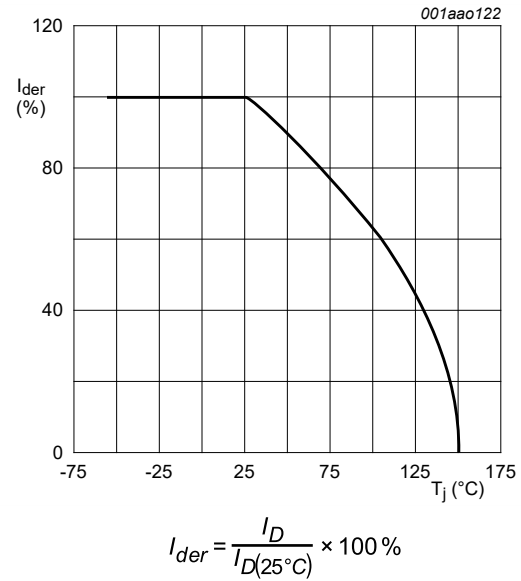
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain  $1\text{ cm}^2$ .

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper; tin-plated and standard footprint.

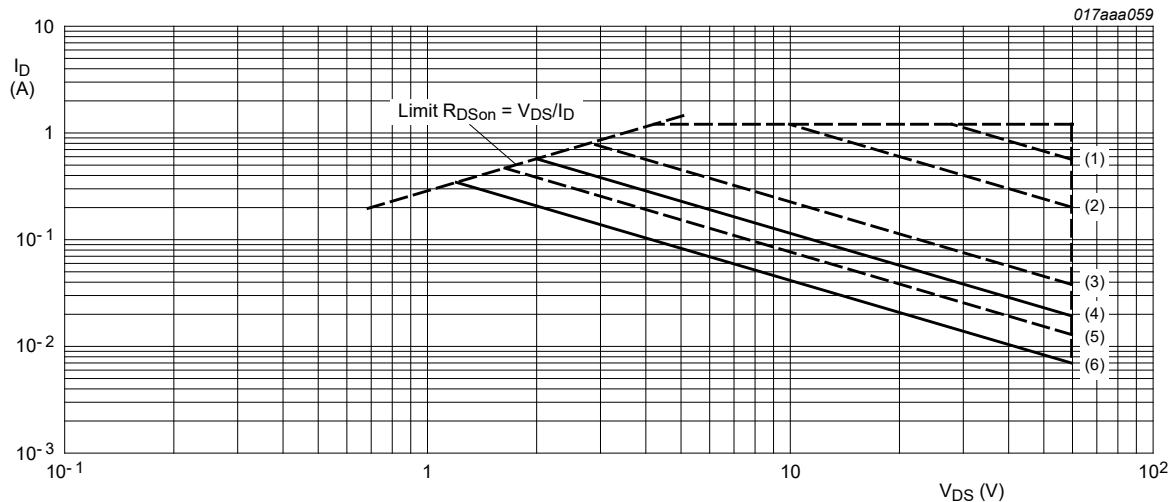
[3] Measured between all pins.



**Fig. 1.** Normalized total power dissipation as a function of junction temperature



**Fig. 2.** Normalized continuous drain current as a function of junction temperature



$I_{DM}$  = single pulse

(1)  $t_p = 100\ \mu\text{s}$

(2)  $t_p = 1\ \text{ms}$

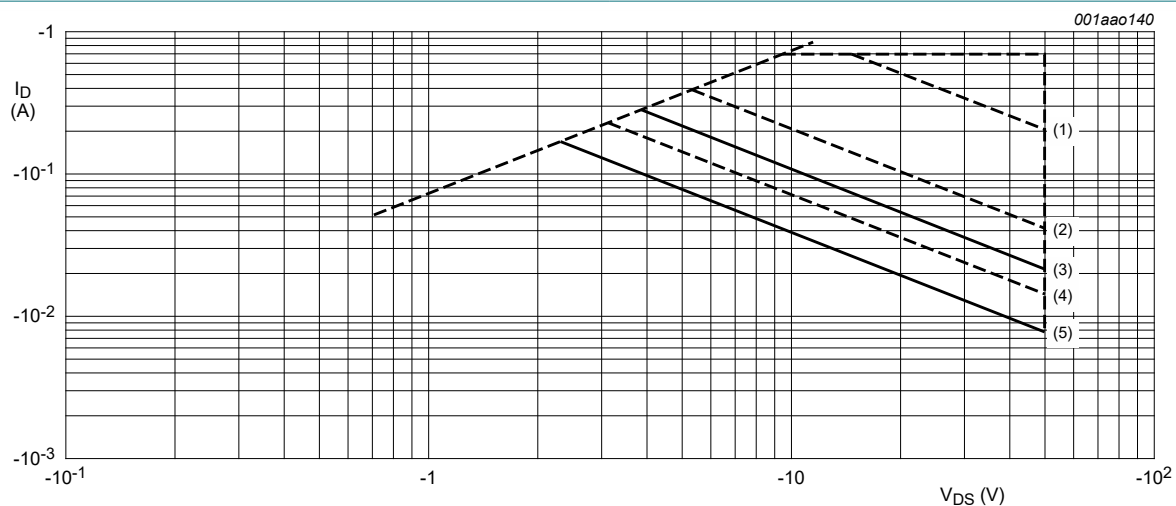
(3)  $t_p = 10\ \text{ms}$

(4) DC;  $T_{sp} = 25\ ^{\circ}\text{C}$

(5)  $t_p = 100\ \text{ms}$

(6) DC;  $T_{amb} = 25\ ^{\circ}\text{C}$ ; drain mounting pad  $1\ \text{cm}^2$

**Fig. 3.** Safe operating area TR1 (N-channel); junction to ambient; continuous and peak drain currents as a function of drain-source voltage



$I_{DM}$  is single pulse

(1)  $t_p = 1 \text{ ms}$

(2)  $t_p = 10 \text{ ms}$

(3) DC;  $T_{sp} = 25 \text{ °C}$

(4)  $t_p = 100 \text{ ms}$

(5) DC;  $T_{amb} = 25 \text{ °C}$ ; drain mounting pad  $1 \text{ cm}^2$

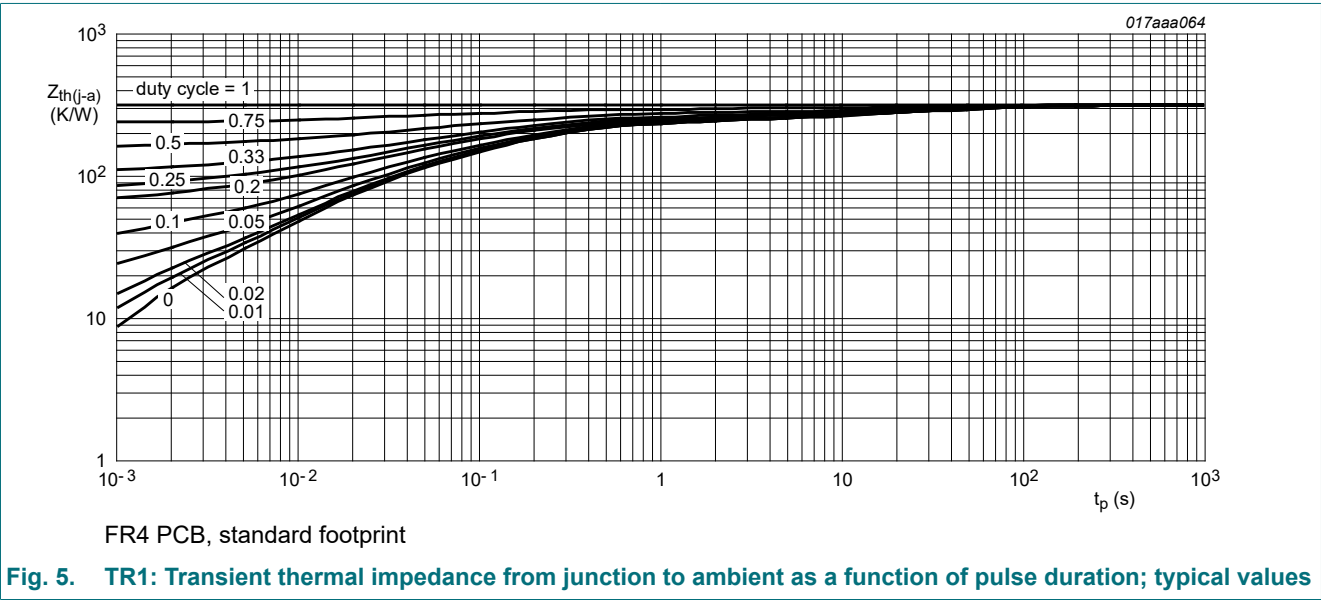
**Fig. 4.** Safe operating area TR2 (P-channel); junction to ambient; continuous and peak drain currents as a function of drain-source voltage

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
TR1 (N-channel)							
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1]	-	330	380	K/W
			[2]	-	280	320	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	-	115	K/W
TR2 (P-channel)							
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1]	-	330	380	K/W
			[2]	-	280	320	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	-	115	K/W
Per device							
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1]	-	-	250	K/W

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper; tin-plated and standard footprint.  
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 1 cm<sup>2</sup>.



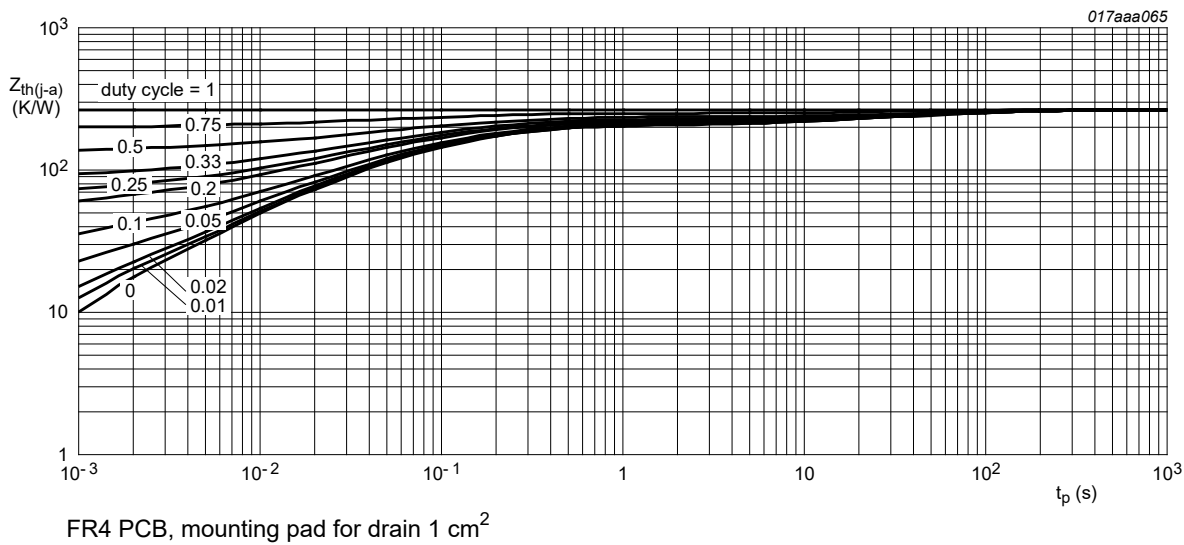


Fig. 6. TR1: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

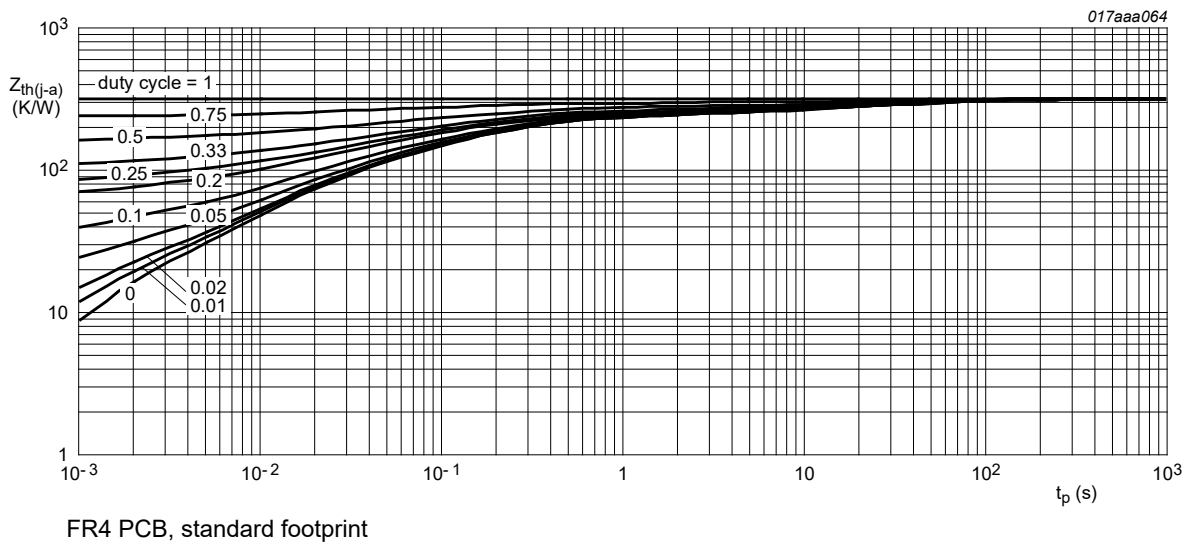


Fig. 7. TR2: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

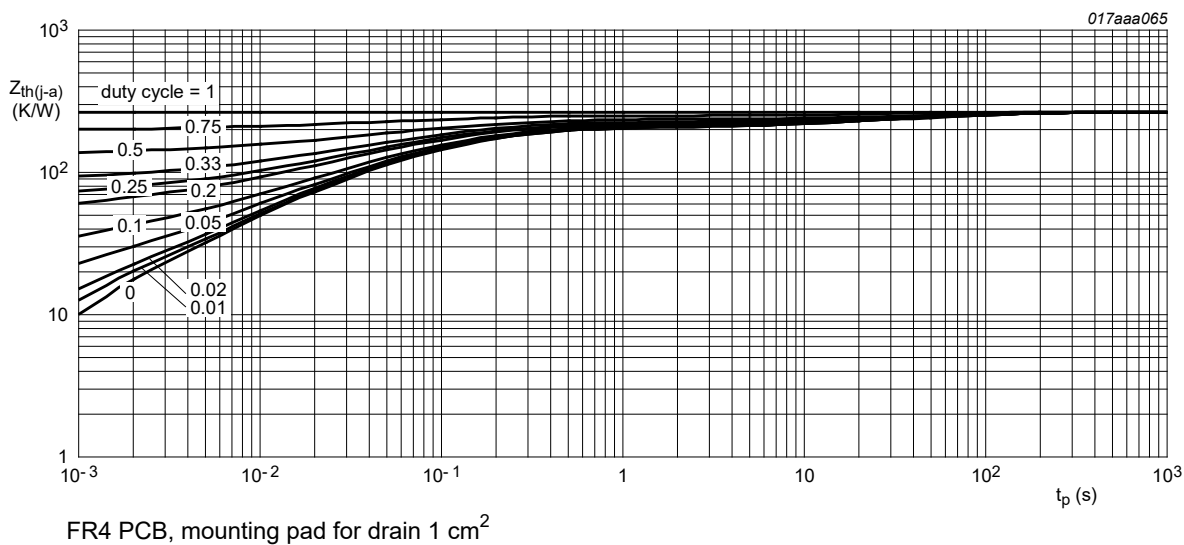


Fig. 8. TR2: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

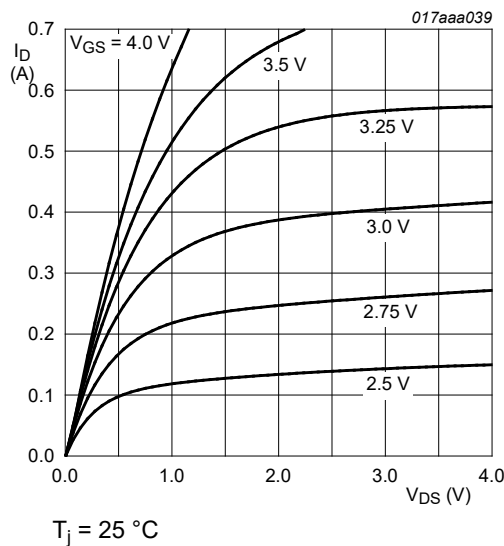
## 10. Characteristics

Table 7. Characteristics

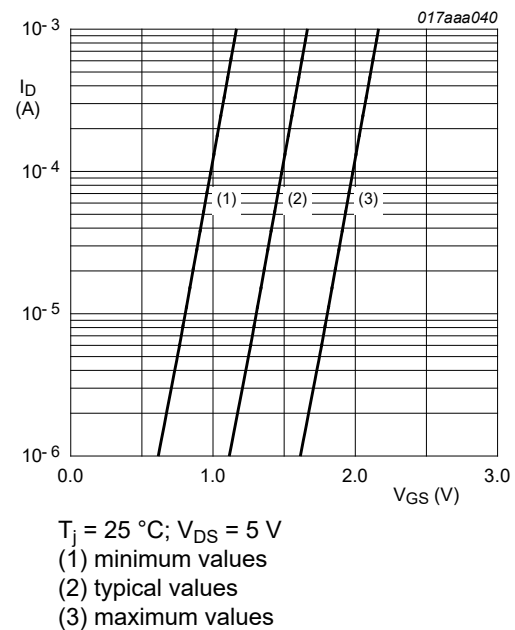
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>TR1 (N-channel), Static characteristics</b>						
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = 10 \mu A$ ; $V_{GS} = 0 V$ ; $T_j = 25^\circ C$	60	-	-	V
$V_{GSth}$	gate-source threshold voltage	$I_D = 250 \mu A$ ; $V_{DS} = V_{GS}$ ; $T_j = 25^\circ C$	1.1	1.6	2.1	V
$I_{DSS}$	drain leakage current	$V_{DS} = 60 V$ ; $V_{GS} = 0 V$ ; $T_j = 25^\circ C$	-	-	1	$\mu A$
		$V_{DS} = 60 V$ ; $V_{GS} = 0 V$ ; $T_j = 150^\circ C$	-	-	10	$\mu A$
$I_{GSS}$	gate leakage current	$V_{GS} = 20 V$ ; $V_{DS} = 0 V$ ; $T_j = 25^\circ C$	-	-	10	$\mu A$
		$V_{GS} = -20 V$ ; $V_{DS} = 0 V$ ; $T_j = 25^\circ C$	-	-	10	$\mu A$
$R_{DSon}$	drain-source on-state resistance	$V_{GS} = 10 V$ ; $I_D = 500 mA$ ; pulsed; $t_p \leq 300 \mu s$ ; $\delta \leq 0.01$ ; $T_j = 25^\circ C$	-	1	1.6	$\Omega$
		$V_{GS} = 10 V$ ; $I_D = 500 mA$ ; pulsed; $t_p \leq 300 \mu s$ ; $\delta \leq 0.01$ ; $T_j = 150^\circ C$	-	2.25	3.6	$\Omega$
		$V_{GS} = 5 V$ ; $I_D = 50 mA$ ; pulsed; $t_p \leq 300 \mu s$ ; $\delta \leq 0.01$ ; $T_j = 25^\circ C$	-	1.3	2	$\Omega$
$g_{fs}$	forward transconductance	$V_{DS} = 10 V$ ; $I_D = 100 mA$ ; $T_j = 25^\circ C$	-	550	-	mS
<b>TR2 (P-channel), Static characteristics</b>						
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = -10 \mu A$ ; $V_{GS} = 0 V$ ; $T_j = 25^\circ C$	-50	-	-	V
$V_{GSth}$	gate-source threshold voltage	$I_D = -250 \mu A$ ; $V_{DS} = V_{GS}$ ; $T_j = 25^\circ C$	-1.1	-1.6	-2.1	V
$I_{DSS}$	drain leakage current	$V_{DS} = -50 V$ ; $V_{GS} = 0 V$ ; $T_j = 25^\circ C$	-	-	-1	$\mu A$
		$V_{DS} = -50 V$ ; $V_{GS} = 0 V$ ; $T_j = 150^\circ C$	-	-	-2	$\mu A$
$I_{GSS}$	gate leakage current	$V_{GS} = 20 V$ ; $V_{DS} = 0 V$ ; $T_j = 25^\circ C$	-	-	-10	$\mu A$
		$V_{GS} = -20 V$ ; $V_{DS} = 0 V$ ; $T_j = 25^\circ C$	-	-	-10	$\mu A$
$R_{DSon}$	drain-source on-state resistance	$V_{GS} = -10 V$ ; $I_D = -100 mA$ ; $T_j = 25^\circ C$	-	4.5	7.5	$\Omega$
		$V_{GS} = -10 V$ ; $I_D = -100 mA$ ; $T_j = 150^\circ C$	-	8	13.5	$\Omega$
		$V_{GS} = -5 V$ ; $I_D = -100 mA$ ; $T_j = 25^\circ C$	-	5.1	8.5	$\Omega$
$g_{fs}$	forward transconductance	$V_{DS} = -10 V$ ; $I_D = -100 mA$ ; $T_j = 25^\circ C$	-	150	-	mS
<b>TR1 (N-channel), Dynamic characteristics</b>						
$Q_{G(tot)}$	total gate charge	$V_{DS} = 30 V$ ; $I_D = 300 mA$ ; $V_{GS} = 4.5 V$ ; $T_j = 25^\circ C$	-	0.5	0.6	nC
$Q_{GS}$	gate-source charge		-	0.2	-	nC
$Q_{GD}$	gate-drain charge		-	0.1	-	nC
$C_{iss}$	input capacitance	$V_{DS} = 10 V$ ; $f = 1 MHz$ ; $V_{GS} = 0 V$ ; $T_j = 25^\circ C$	-	33	50	pF
$C_{oss}$	output capacitance		-	7	-	pF
$C_{rss}$	reverse transfer capacitance		-	4	-	pF
$t_{d(on)}$	turn-on delay time	$V_{DS} = 50 V$ ; $R_L = 250 \Omega$ ; $V_{GS} = 10 V$ ; $R_{G(ext)} = 6 \Omega$ ; $T_j = 25^\circ C$	-	5	10	ns
$t_r$	rise time		-	6	-	ns
$t_{d(off)}$	turn-off delay time		-	12	24	ns
$t_f$	fall time		-	7	-	ns



Symbol	Parameter	Conditions		Min	Typ	Max	Unit
TR2 (P-channel), Dynamic characteristics							
Q <sub>G(tot)</sub>	total gate charge	V <sub>DS</sub> = -25 V; I <sub>D</sub> = -180 mA; V <sub>GS</sub> = -5 V; T <sub>j</sub> = 25 °C		-	0.26	0.35	nC
Q <sub>GS</sub>	gate-source charge			-	0.12	-	nC
Q <sub>GD</sub>	gate-drain charge			-	0.09	-	nC
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = -25 V; f = 1 MHz; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C		-	24	36	pF
C <sub>oss</sub>	output capacitance			-	4.5	-	pF
C <sub>rss</sub>	reverse transfer capacitance			-	1.3	-	pF
t <sub>d(on)</sub>	turn-on delay time	V <sub>DS</sub> = -30 V; R <sub>L</sub> = 250 Ω; V <sub>GS</sub> = -10 V; R <sub>G(ext)</sub> = 6 Ω; T <sub>j</sub> = 25 °C		-	13	26	ns
t <sub>r</sub>	rise time			-	11	-	ns
t <sub>d(off)</sub>	turn-off delay time			-	48	96	ns
t <sub>f</sub>	fall time			-	25	-	ns
TR1 (N-channel), Source-drain diode characteristics							
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = 115 mA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C		0.47	0.75	1.1	V
TR2 (P-channel), Source-drain diode characteristics							
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = -115 mA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C		-0.48	-0.85	-1.2	V



**Fig. 9. TR1: Output characteristics: drain current as a function of drain-source voltage; typical values**



**Fig. 10. TR1: Sub-threshold drain current as a function of gate-source voltage**

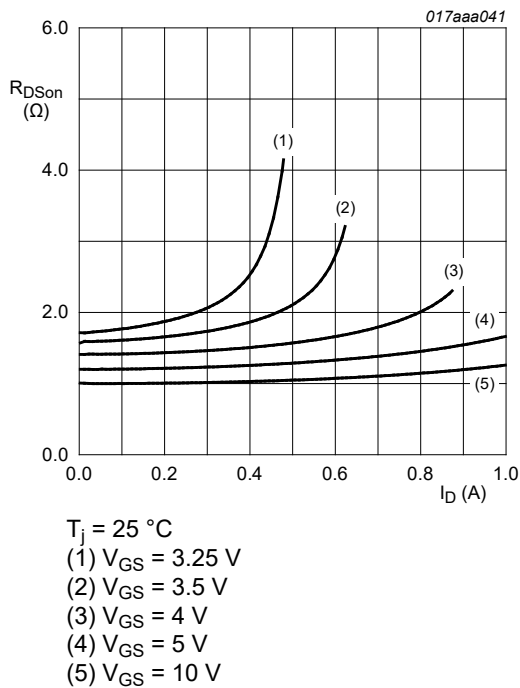


Fig. 11. TR1: Drain-source on-state resistance as a function of drain current; typical values

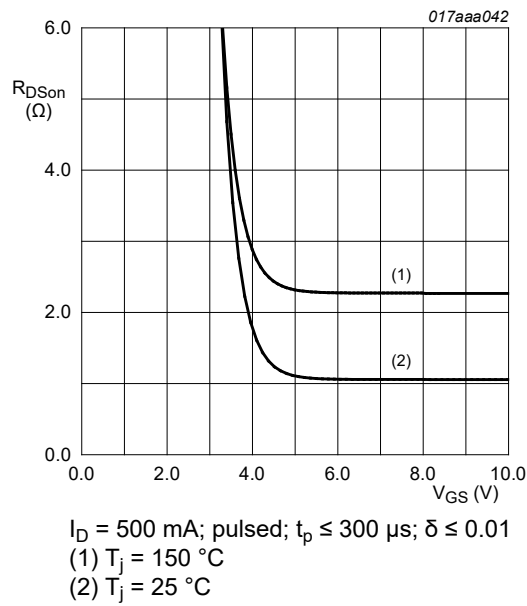


Fig. 12. TR1: Drain-source on-state resistance as a function of gate-source voltage; typical values

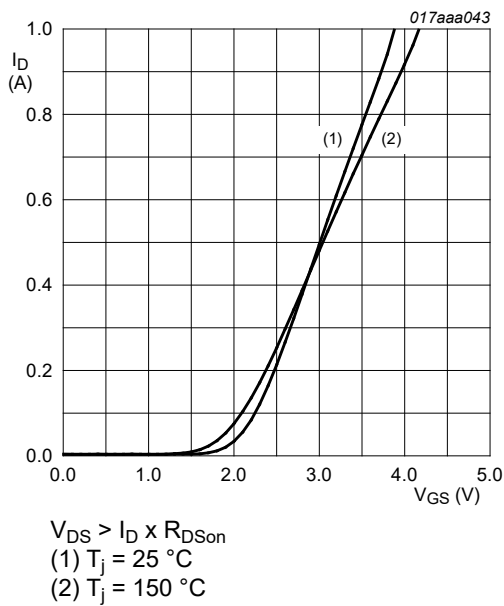


Fig. 13. TR1: Transfer characteristics: drain current as a function of gate-source voltage; typical values

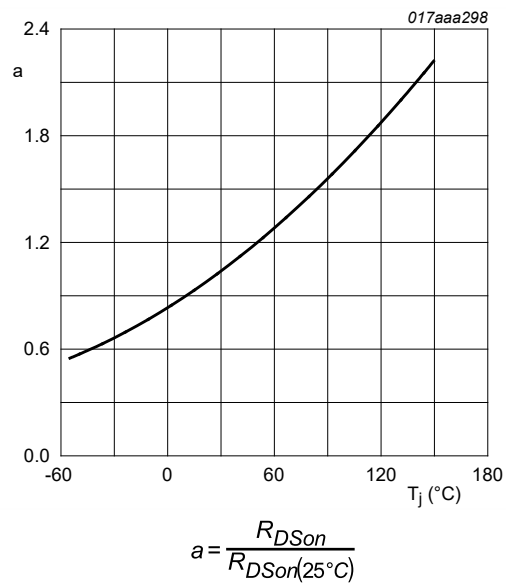


Fig. 14. TR1: Normalized drain-source on-state resistance as a function of junction temperature; typical values

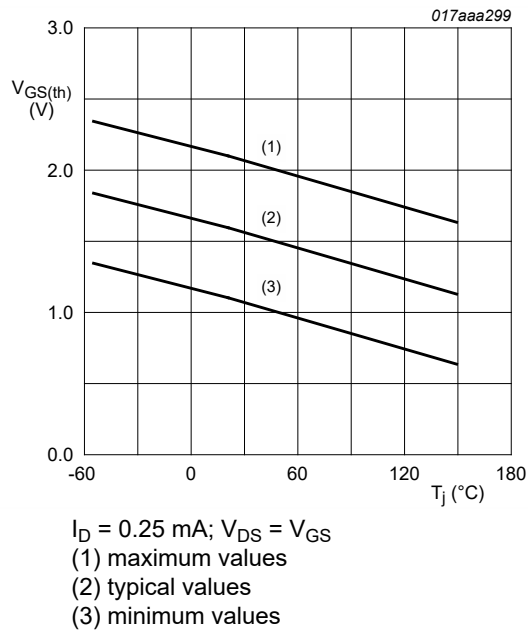


Fig. 15. TR1: Gate-source threshold voltage as a function of junction temperature

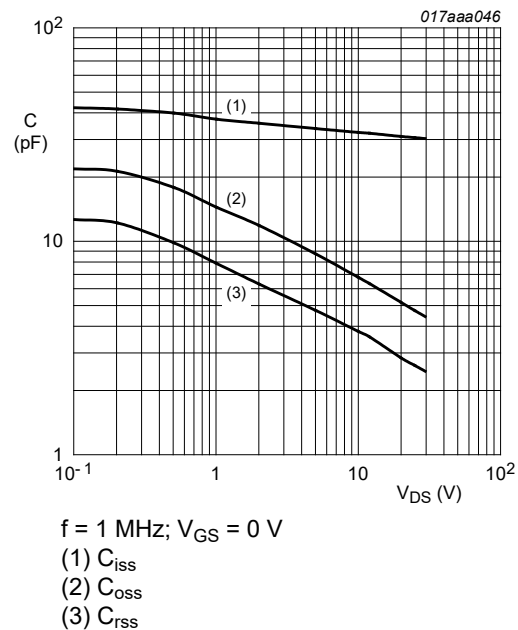


Fig. 16. TR1: Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

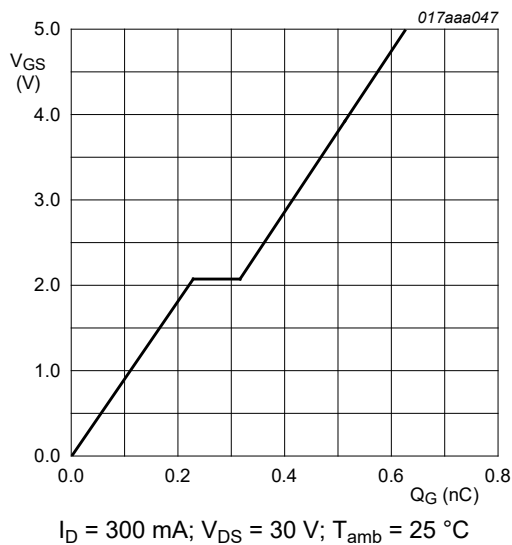


Fig. 17. TR1: Gate-source voltage as a function of gate charge; typical values

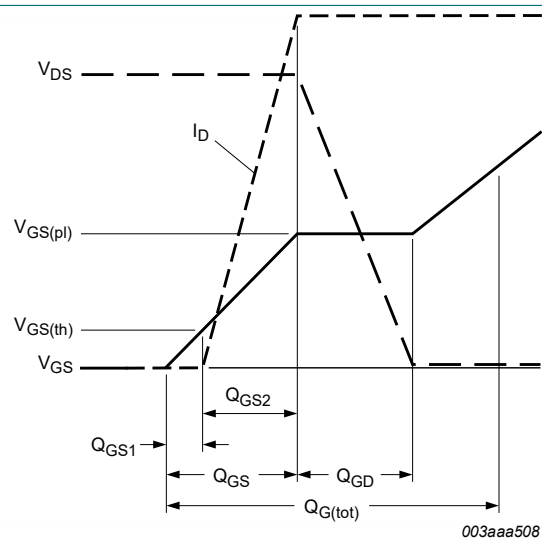


Fig. 18. Gate charge waveform definitions

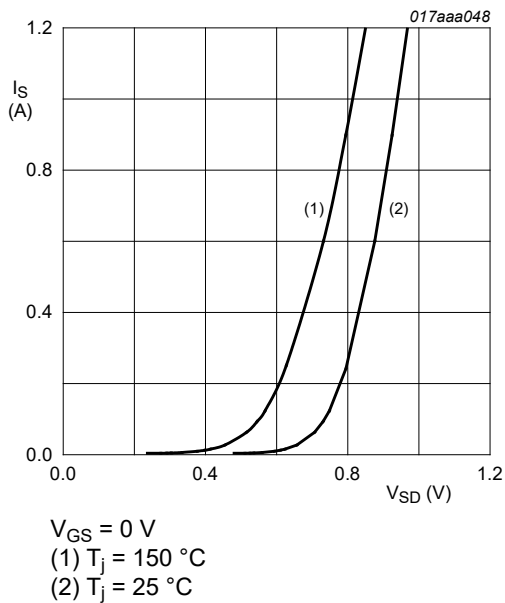


Fig. 19. TR1: Source current as a function of source-drain voltage; typical values

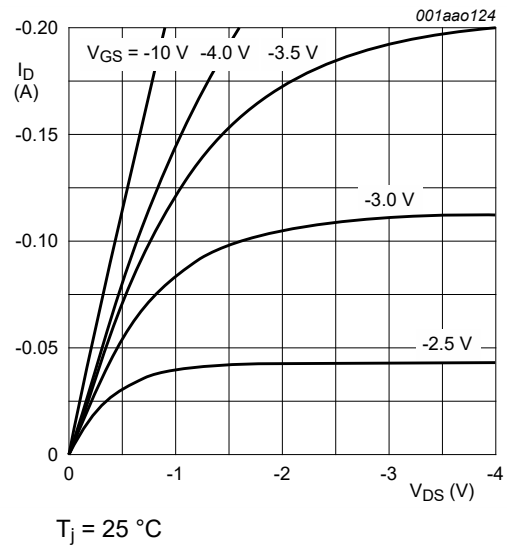


Fig. 20. TR2: Output characteristics: drain current as a function of drain-source voltage; typical values

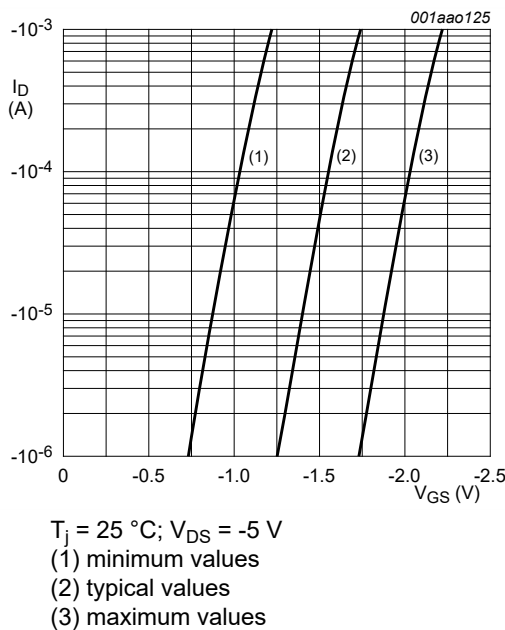


Fig. 21. TR2: Sub-threshold drain current as a function of gate-source voltage

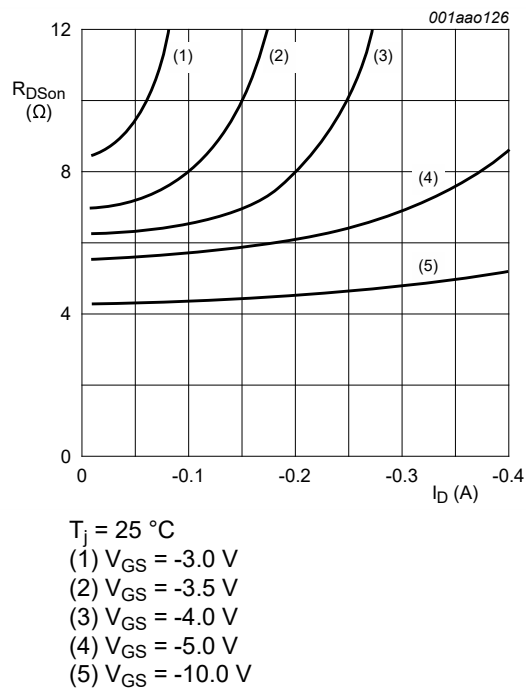


Fig. 22. TR2: Drain-source on-state resistance as a function of drain current; typical values

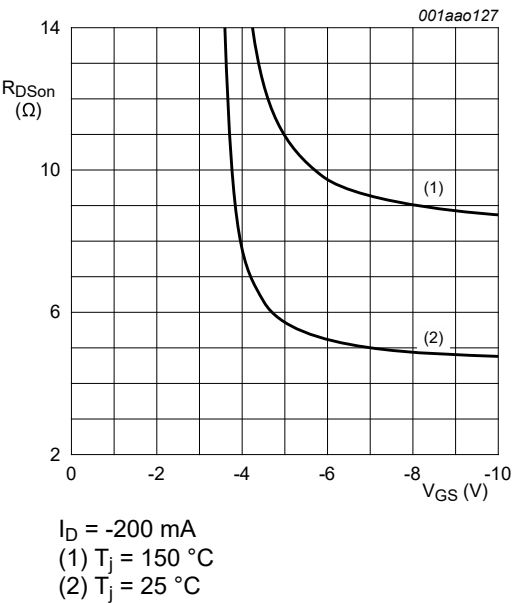


Fig. 23. TR2: Drain-source on-state resistance as a function of gate-source voltage; typical values

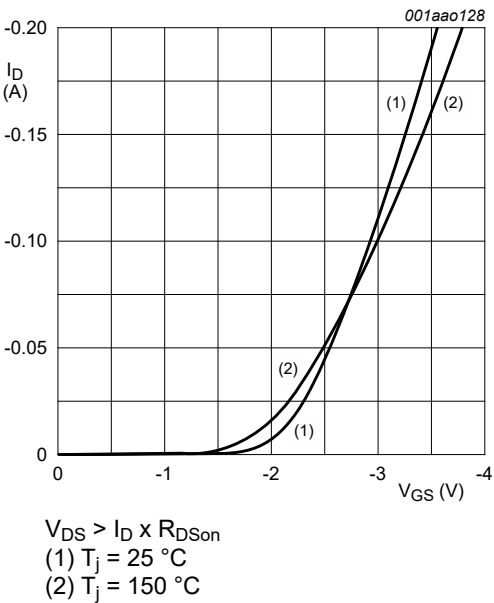


Fig. 24. TR2: Transfer characteristics: drain current as a function of gate-source voltage; typical values

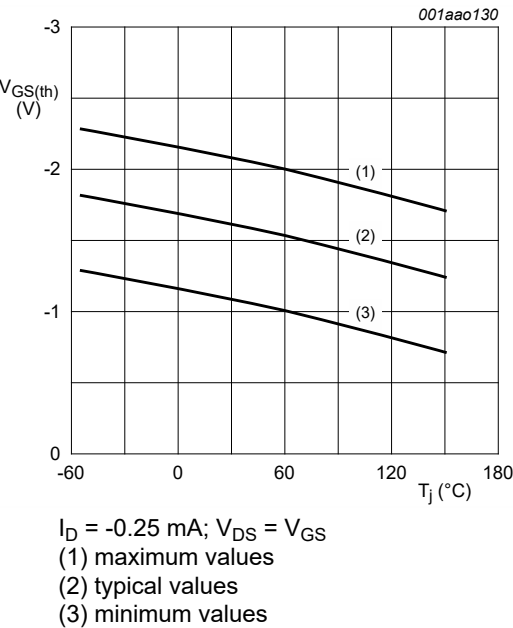


Fig. 25. TR2: Gate-source threshold voltage as a function of junction temperature

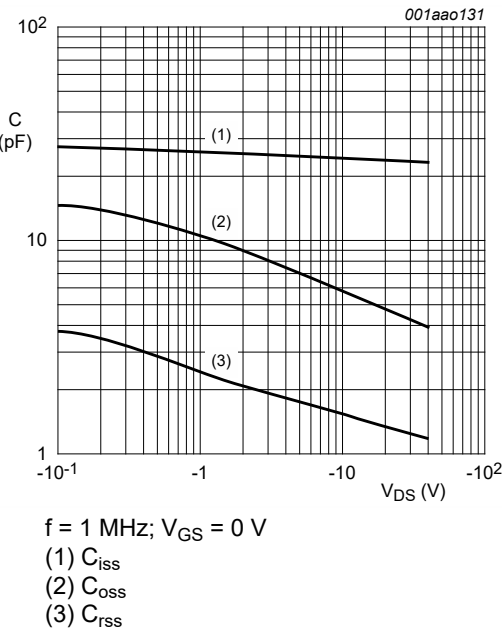
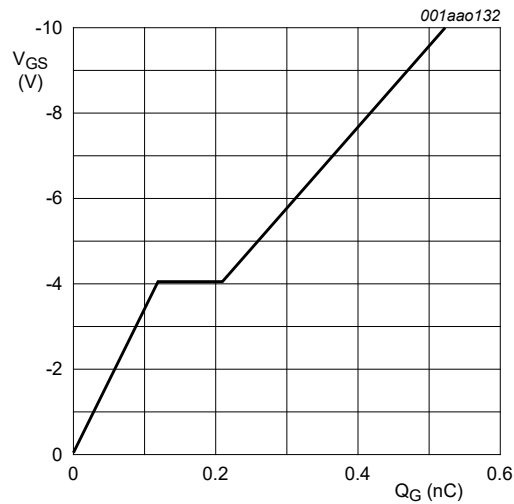
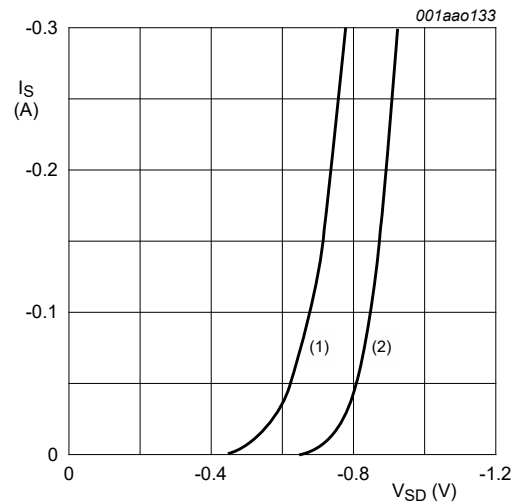


Fig. 26. TR2: Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values



$I_D = -200\text{ mA}$ ;  $V_{DS} = -25\text{ V}$ ;  $T_{amb} = 25\text{ }^{\circ}\text{C}$

Fig. 27. TR2: Gate-source voltage as a function of gate charge; typical values



$V_{GS} = 0\text{ V}$   
(1)  $T_j = 150\text{ }^{\circ}\text{C}$   
(2)  $T_j = 25\text{ }^{\circ}\text{C}$

Fig. 28. TR2: Source current as a function of source-drain voltage; typical values

11. Test information

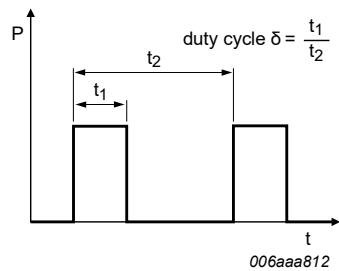
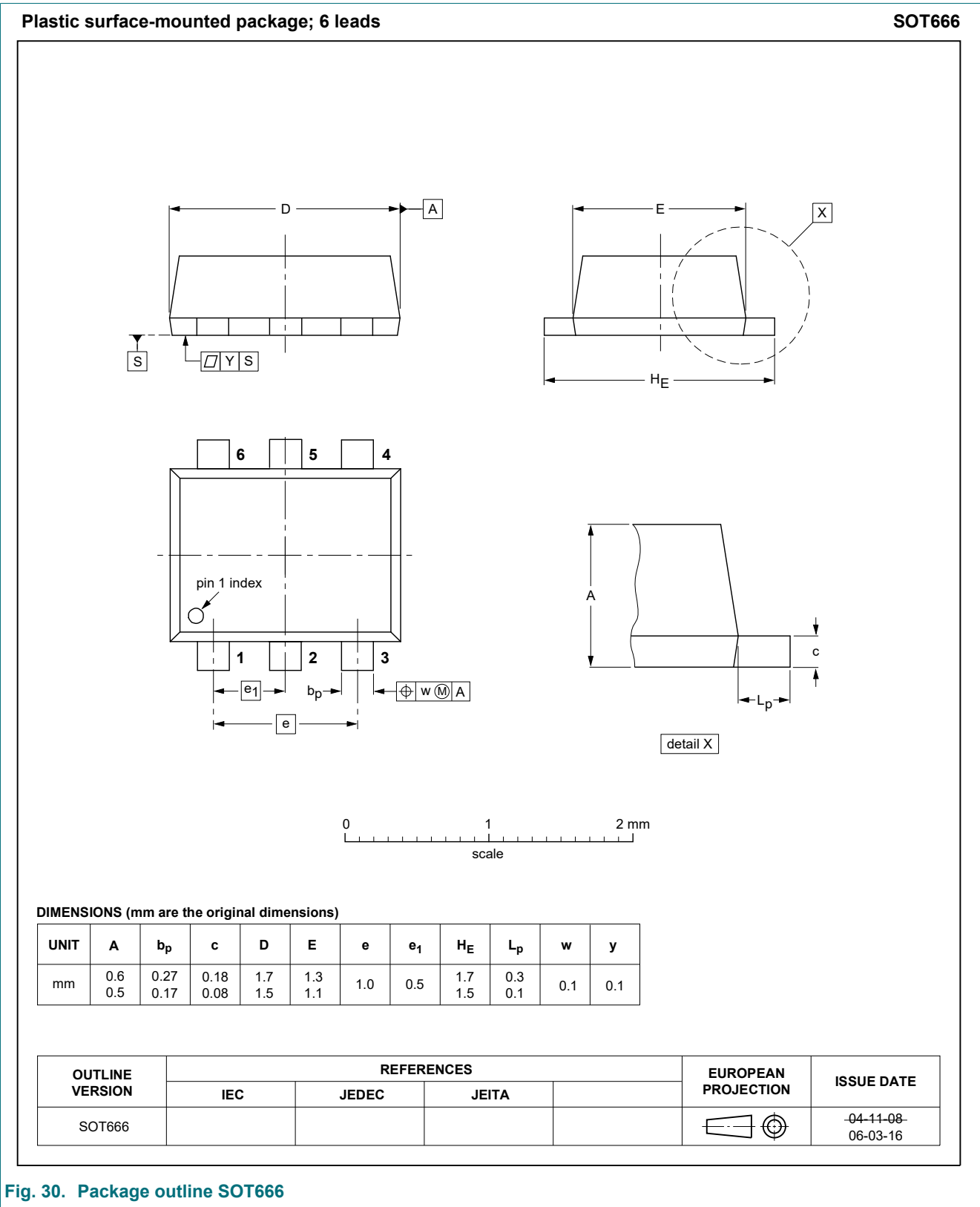


Fig. 29. Duty cycle definition

12. Package outline



13. Soldering

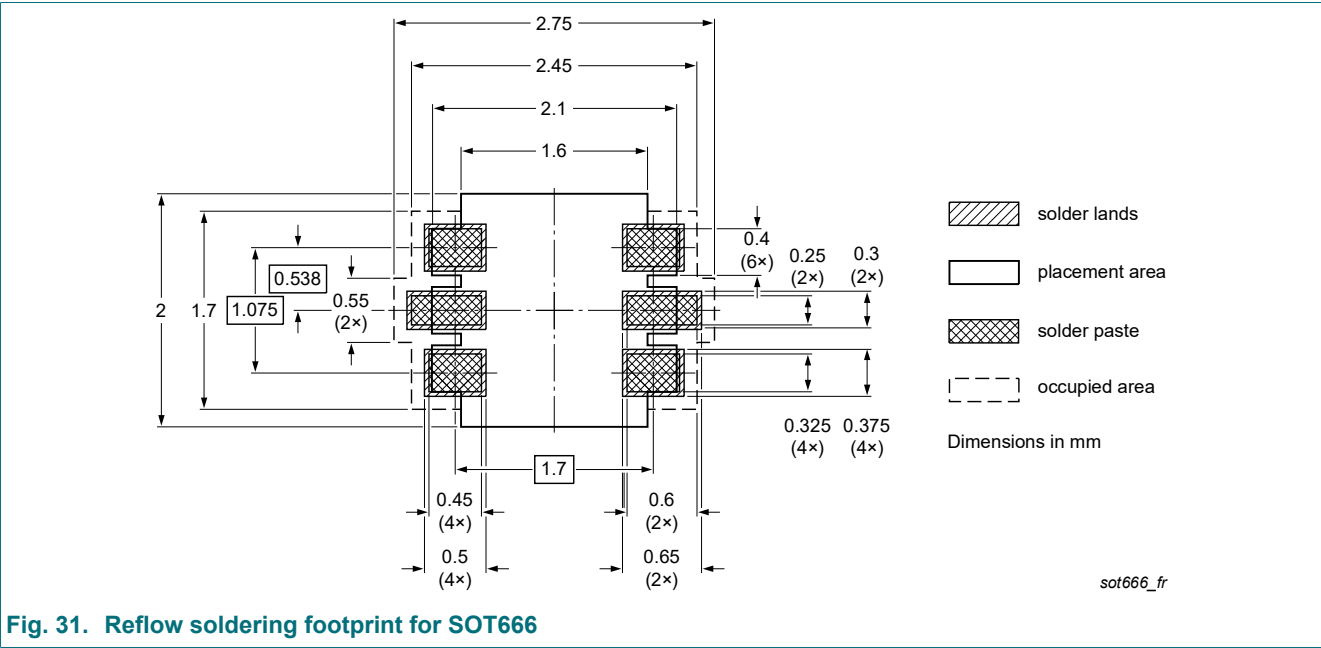


Fig. 31. Reflow soldering footprint for SOT666



## 14. Revision history

**Table 8. Revision history**

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
NX1029X v.2	20221228	Product data sheet	-	NX1029X v.1
Modifications:	<ul style="list-style-type: none"><li>• The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia</li><li>• Legal texts have been adapted to the new company name where appropriate</li><li>• Product changed to non-automotive qualification</li></ul>			
NX1029X v.1	20110812	Product data sheet	-	-

## 15. Legal information

### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <https://www.nexperia.com>.

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